

NCE P-Channel Enhancement Mode Power MOSFET

Description

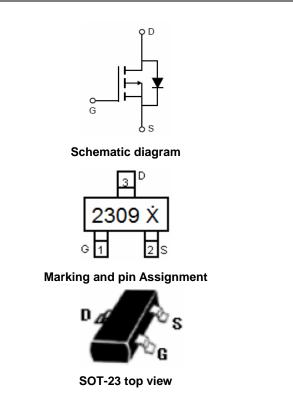
The NCE2309 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge .This device is well suited for use as a load switch or in PWM applications.

General Features

- V_{DS} =-60V,I_D =-1.6A
 R_{DS(ON)} <160mΩ @ V_{GS}=-10V
 R_{DS(ON)} <200mΩ @ V_{GS}=-4.5V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

Application

- Load switch
- PWM application



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2309 ×	NCE2309	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_c=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι _D	-1.6	А
Pulsed Drain Current (Note 1)	I _{DM}	-8	А
Maximum Power Dissipation	PD	1.5	W
Operating Junction and Storage Temperature Range	T_{J},T_{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient ^(Note 2)	R _{θJA}	83.3	°C /W
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Electrical Characteristics (T_C=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-60V, V_{GS} =0V	-	-	-1	μA



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Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	·					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-1.4	-2.0	-2.6	V
Drain-Source On-State Resistance	R _{DS(ON)} -	V _{GS} =-10V, I _D =-1.5A	-	140	160	mΩ
Drain-Source On-State Resistance		V _{GS} =-4.5V, I _D =-1.5A	-	160	200	mΩ
Forward Transconductance	g fs	V _{DS} =-5V,I _D =-1.5A	-	3	-	S
Dynamic Characteristics (Note4)	·					
Input Capacitance	C _{lss}		-	444.2	-	PF
Output Capacitance	C _{oss}	V _{DS} =-30V,V _{GS} =0V, F=1.0MHz	-	19.6	-	PF
Reverse Transfer Capacitance	C _{rss}		-	17.9	-	PF
Switching Characteristics (Note 4)	·					
Turn-on Delay Time	t _{d(on)}		-	40	-	nS
Turn-on Rise Time	tr	V _{DD} =-30V, I _D =-1.5A,	-	35	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10V,R _G =3 Ω	-	15	-	nS
Turn-Off Fall Time	t _f		-	10	-	nS
Total Gate Charge	Qg		-	11.3	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =-30, I_{D} =-1.5A,	-	2.7	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =-10V	-	1.6	-	nC
Drain-Source Diode Characteristics	·					
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-1.5A	-		-1.2	V
Diode Forward Current (Note 2)	Is		-	-	-1.6	А
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F =- 1.5A	-	25		nS
Reverse Recovery Charge	Qrr	di/dt = -100A/µs ^(Note3)	-	31		nC

Notes:

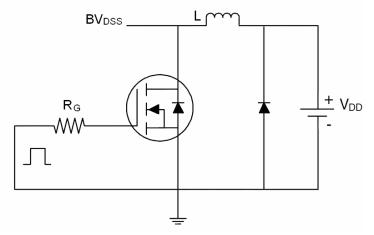
1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec. **3.** Pulse Test: Pulse Width $\le 300 \mu$ s, Duty Cycle $\le 2\%$.

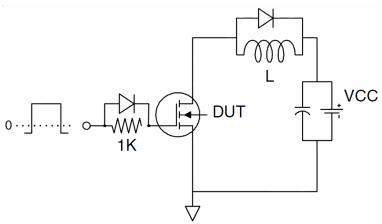
4. Guaranteed by design, not subject to production



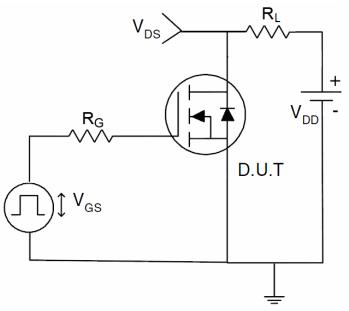
Test Circuit 1) E_{AS} test Circuit



2) Gate charge test Circuit

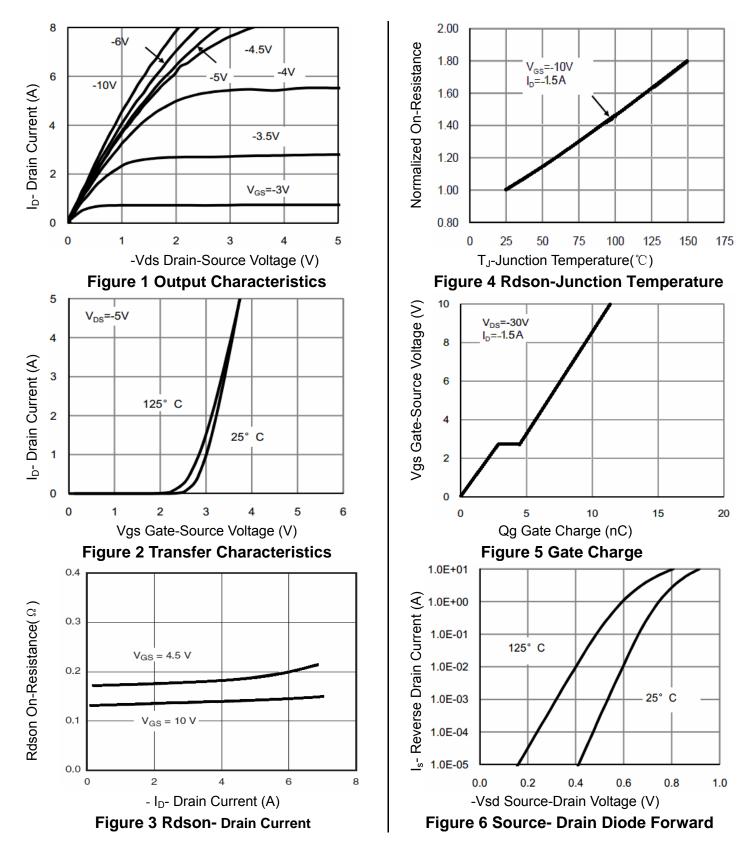


3) Switch Time Test Circuit





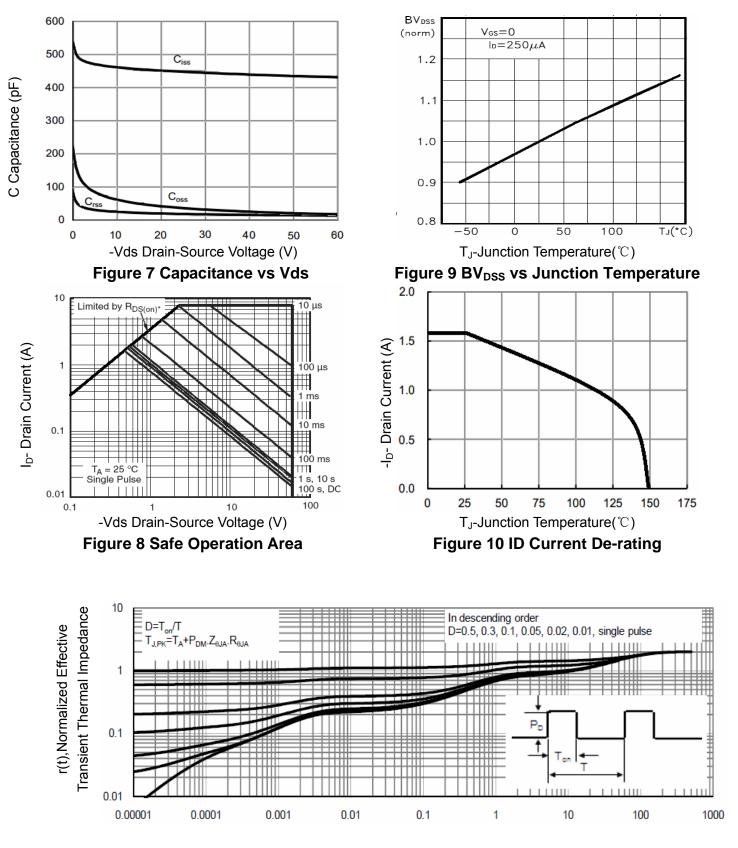
Typical Electrical and Thermal Characteristics (Curves)





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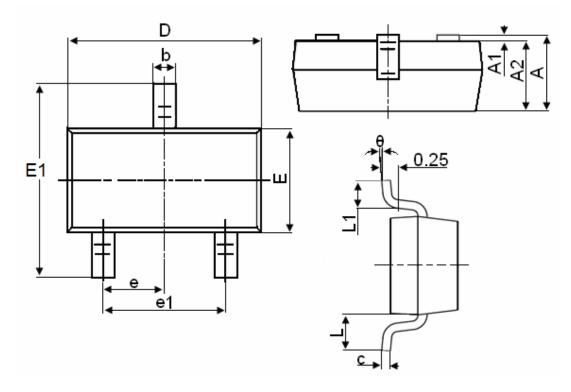


Square Wave Pluse Duration(sec) Figure 11 Normalized Maximum Transient Thermal Impedance



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SOT-23 Package Information



Symbol		Dimensions in Millimeters		
Symbol	MIN.	MAX.		
A	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
с	0.080	0.150		
D	2.800	3.000		
E	1.200	1.400		
E1	2.250	2.550		
е		0.950TYP		
e1	1.800	2.000		
L		0.550REF		
L1	0.300	0.500		
θ	0°	8°		

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ± 0.10 mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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